



# United Silicon Carbide, Inc.

## Product Qualification Report

Discrete D2PAK-7L Side-By-Side Cascode Devices

Included Products:

**D2PAK-7L**

UF3SC065030B7S

UF3SC0650400B7S

UF3SC120040B7S

This report summarizes the qualification results for the 650V and 1200V UF3C Discrete SiC Stacked Cascodes in D2PAK-7L (TO-263-7L) plastic packages.

The environmental stress tests listed below are performed with pre-stress and post-stress electrical tests. Reviewing the electrical results for new failures and any significant shift in performance satisfies the qualification requirements.

### Reliability Stress Test Summary

Test Name	MSL 3 Precon	Test Standard	# Samples x # Lots	Failures
MSL3 Pre Conditioning		JESD22-A113D T=60°C, RH=60%, 40hrs + 3x IR reflow	77 pcs per lot, 3 lots per test, 4 tests	0/924
High Temperature Reverse Bias (HTRB)		MIL-STD-750-1 M1038 Method A (1000 Hours) T <sub>J</sub> =175°C, V=80% V <sub>max</sub>	77 pcs per lot x 3 lots	0/231
High Temperature Gate Bias (HTGB)		JESD22 A-108 (1000 Hours) T <sub>J</sub> =175°C, V=100% V <sub>max</sub> (+20V), bias in one direction	77 pcs per lot x 3 lots	0/231
High Humidity, High Temperature Reverse Bias (H3TRB)	Y	JESD22-A101C (1000 Hours) T <sub>A</sub> =85°C, 85% RH, V <sub>GS</sub> =0V, V <sub>DS</sub> =100V	77 pcs per lot x 3 lots	0/231
Temperature Cycle (TC)	Y	JESD22 A-104 -55°C to +150°C 2 cycles/Hr, 1000 cycles	77 pcs per lot x 3 lots	0/231
Autoclave (PCT)	Y	JESD22 A-102 121°C/ RH = 100%, 96 hours, 15psig	77 pcs per lot x 3 lots	0/231
Intermittent Operating Life	Y	MIL-STD-750 Method 1037 DTJ ≥125°C, 3000 cycles (5 minutes on/ 5 minutes off)	77 pcs per lot x 3 lots	0/231

Parametric Verification		Per Datasheet	100% FT x 3 lots	
Physical Dimensions		Per AEC-Q101 Rev D	30x1 packages	0/30
Bondline Thickness		Per Assembly Spec	10x3 lots	0/30
Die Shear		Per Assembly Spec	10x3 lots	0/30
Die Attach Voids		Per Assembly Spec	10x3 lots	0/30
Wire Pull		Per Assembly Spec	10x3 lots	0/30
Wedge Shear		Per Assembly Spec	10x3 lots	0/30
CSAM		Per Assembly Spec	60x3 lots	0/180
Lead Integrity Test		Per AEC-Q101 Rev D	30x1 lots	0/30
Solderability Test		Per AEC-Q101 Rev D	10x1 lots	0/10

### Reliability Evaluation:

The FIT rate data presented below is determined according to JEDEC Standard JESD 85 and is determined from the HTRB and HTGB Burn-In sample size.

**FIT = 2.608009298 failures per billion device hours**

**MTTF = 43771.03 years**

From the equations:

$$\lambda_{hours} = \frac{X^2(\alpha, \nu)}{2 \times D \times H \times A_f}$$

$$FIT = \lambda_{hours} \times 10^9$$

$$MTTF_{hours} = 1/\lambda_{hours}$$

And

$$A_f = e^{\frac{E_a}{k} \left( \frac{1}{T_{use}} - \frac{1}{T_{test}} \right)}$$



Where:

$\chi^2$  = Chi-Squared probability function for a given Confidence Level ( $\alpha$ ) and Degree of Freedom ( $\nu = 2r+2$ , where  $r$  = the number of failures in the Test Population),

$D$  = Number of Devices in the Test Population,

$H$  = Test Hours per Device,

$A_f$  = Acceleration Factor from the Arrhenius equation,

$E_a$  = Activation Energy (eV),

$T_{use}$  = standardized Use Temperature,

$T_{test}$  = Temperature of Stress Test,

and

$k$  = Boltzmann's Constant.

In our calculations, we used our HTGB and HTRB Burn-In data:

$D$  = 231 devices for HTGB and 231 for HTRB,

$H$  = 1000 hours for HTGB and 1000 hours of HTRB,

$1 - \alpha = 0.6$  (60% Confidence Level)

$r = 0$  Failures

$E_a = 0.7$  eV

$T_{use} = 55$  °C or 328 K

$T_{test} = 175$  °C or 448 K